UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/511,734	10/18/2004	Davor Protic	046972-0102	2536
	7590 07/30/201 LARDNER LLP	0	EXAM	IINER
SUITE 500 3000 K STREET NW WASHINGTON, DC 20007			LEE, SHUN K	
			ART UNIT	PAPER NUMBER
			2884	
			MAIL DATE	DELIVERY MODE
			07/30/2010	PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

1	
2	
3	RECORD OF ORAL HEARING
4	UNITED STATES PATENT AND TRADEMARK OFFICE
5	
6	BEFORE THE BOARD OF PATENT APPEALS
7	AND INTERFERENCES
8	
9	E DAVOD DDOTEC ATHOMAS VDINOS
10	Ex parte DAVOR PROTIC and THOMAS KRINGS
11 12	
13	Appeal 2009-012467
14	Application 10/511,734
15	Technology Center 2800
16	
17	
18	Oral Hearing Held: June 23, 2010
19 20	
20	
22	Before ROBERT E. NAPPI, JOHN C. MARTIN, JOSEPH F. RUGGIERO,
23	Administrative Patent Judges.
24	
25	
26	ON BEHALF OF THE APPELLANT:
27	
28 29	KEVIN MCHENRY, ESQ.
30	3000 K Street, N.W.
31	Washington, D.C. 20007
32	(202) 295-4011
33	
3/1	

1 The above-entitled matter came on for hearing on Tuesday, June 23, 2010, commencing at 9:58 a.m., at the U.S. Patent and Trademark Office, 600 Dulany Street, 9th Floor, Alexandria, Virginia, before Lori Beth Allen, Notary Public. 5 JUDGE NAPPI: Good morning, Mr. McHenry. 6 MR. MCHENRY: Good morning. 7 JUDGE NAPPI: You have 20 minutes. But before you start, 8 can you give the stenographer a copy of your business card, so she gets the spelling of your name proper on the record? 10 And also so she can contact you in case there's any questions? 11 MR. MCHENRY: Actually, I don't think I have a copy, or I 12 have a business card, to tell you the truth. 13 JUDGE NAPPI: Can you just spell your name for the record? 14 MR. MCHENRY: Sure. Thank you. K-e-v-i-n and my last 15 name, M-c-H-e-n-r-y. 16 JUDGE NAPPI: You may begin. 17 MR. MCHENRY: Okay. 18 Well, thank you for your time today. I'd like to begin by 19 actually just addressing the Examiner's rejection, and in the Examiner's 20 rejection, the Examiner relies heavily on equivalents. 21 The Examiner argues that the secondary reference in the 22 obviousness rejection Luke teaches equivalence for amorphous germanium 23 contacts, and what I'll call doped contacts, contacts formed by doping 24 elements such as lithium, boron, phosphorus, elements of that nature, and 25 saying that it would just simply be obvious to substitute the doped contact of

1 the base reference by the amorphous germanium contact of the secondary 2 reference loop, simply because they're equivalent. And my point is that in reaching this conclusion of obviousness, 3 4 using this rationale of equivalence, the Examiner has not properly considered the facts and evidence before him, and particularly the references and the knowledge that one of ordinary skill in the art, and that there is no equivalence, there is no teaching of equivalence for these two features. 8 And first of all, the Applicant's own specification shows that amorphous germanium contacts have lower energy resolution than, say, the dope contacts, and that they would function differently and provide different 10 11 results. 12 JUDGE MARTIN: Mr. McHenry, that part of the spec you're 13 talking about, are you referring to page 5, that first paragraph, that says, 14 "Comparatively poor resolution has been achieved"? 15 MR. MCHENRY: Yes. 16 JUDGE MARTIN: So we don't have any data? We don't know how much work the energy resolution is? Just that statement? 17 18 MR. MCHENRY: That's correct. 19 JUDGE MARTIN: All right. 20 MR. MCHENRY: That's correct. 21 Further, the Declaration provided by Mr. Protic, the final 22 paragraph on page 2, where he spoke of the test, where the test showed that 23 using amorphous germanium contacts provided lower energy resolution, that 24 also shows that there is not equivalence between these doped contacts and 25 the amorphous germanium contacts, and that you the lower energy 26 resolution, though, than you would normally expect from the doped contacts

1	And also Luke itself just simply does not provide the teaching
2	of equivalence. Luke I'll turn to that, my copy Luke itself on the second
3	page, which is page 591, there is a Figure 3, and I'm sorry, the first full
4	paragraph on the second column on page 591, that last sentence, it talks
5	about that amorphous germanium contacts that were used and tested, and
6	says that the amorphous N-plus device showed a much higher leakage
7	current than amorphous P-P-plus and conventional devices.
8	You know, you would actually have different results than we'd
9	see than with the conventional device.
10	So although Luke itself and as the Examiner pointed out in
11	essentially the next paragraph there, in the second column of page 591, the
12	first sentence it says that "amorphous germanium contacts can replace the
13	other contacts of the detector," it's saying that they're different.
14	It's not saying they're equivalent. It's saying that they're
15	different. They have different function or I'm sorry, different
16	performance, different results. And it's not a simple matter of just replacing
17	one with another.
18	And so the Examiner cannot rely on a rationale of equivalence
19	in obtaining that conclusion of obviousness.
20	And if you really studied these facts and evidence that would
21	underlie such a conclusion of obviousness, one wouldn't find support for a
22	rationale or equivalence.
23	JUDGE RUGGIERO: I have a question about your
24	interpretation of Figure 3 here.
25	MR. MCHENRY: Yes. Mm-hmm.

1 JUDGE RUGGIERO: It seems like in your writings in the Reply Brief, you're referring to the graph line on the far right. 3 MR. MCHENRY: Yes. 4 JUDGE RUGGIERO: But that is not -- the A-N and N-plus, that's not the replacement of boron. Boron is P. 5 6 So when you replace boron with amorphous germanium, you have a P, which is the line on the far left. 8 MR. MCHENRY: Right. 9 JUDGE RUGGIERO: It seems like it. MR. MCHENRY: Well, excuse me. Are you saying, though, 10 that --11 12 JUDGE RUGGIERO: It just seems that you were focusing 13 attention on the far right. 14 MR. MCHENRY: Right. 15 JUDGE RUGGIERO: But that is not the replacement of boron with amorphous germanium. It's the replacement of an N material with amorphous germanium. 17 18 MR. MCHENRY: Right. 19 JUDGE RUGGIERO: The Examiner is replacing boron with amorphous germanium. That would the line on the left. 20 21 MR. MCHENRY: Now, now -- I'm sorry, the N materials, they 22 would include -- and correct me if I'm wrong -- lithium or phosphorus? 23 JUDGE RUGGIERO: Well, phosphorus is N. Right? 24 MR. MCHENRY: Right. 25 JUDGE RUGGIERO: And boron is P. 26 MR. MCHENRY: Right.

1	JUDGE RUGGIERO: So.
2	MR. MCHENRY: And actually
3	JUDGE RUGGIERO: The Examiner's position is amorphous
4	germanium is an alternative replacement for boron.
5	MR. MCHENRY: Boron being
6	JUDGE RUGGIERO: That's what you might get out of the
7	Examiner's position.
8	MR. MCHENRY: Boron being a positive material?
9	JUDGE RUGGIERO: Well, the first full paragraph on page
10	490 of Luke talks about various types of contacts
11	MR. MCHENRY: Mm-hmm
12	JUDGE MARTIN: Lithium, boron, and I guess phosphorous
13	he talks about in there also.
14	The very beginning of the next paragraph, he says, "An
15	alternative to the contacts discussed above are amorphous contacts."
16	MR. MCHENRY: Mm-hmm.
17	JUDGE MARTIN: So I think the Examiner's let's see what I
18	can find here yeah, I think the bottom of page 8 of the answer says, "Luke
19	teaches to suggest that blocking contacts are selected from one of the
20	following equivalent blocking contacts: Boron, amorphous silicon, or
21	amorphous germanium."
22	So it seems like he's considering amorphous contacts as
23	equivalent to boron.
24	MR. MCHENRY: Yeah. I understand what you're saying.

1	I would rely on my previous statements that I said about the
2	change in energy resolution, that one of ordinary skill in the art would
3	understand there'd be a difference in energy resolution.
4	I'd also point out that Luke itself on the first full paragraph on
5	the second column of 590, Luke even talks about in the final sentence of that
6	paragraph, "preliminary results show that sputtered amorphous germanium
7	contacts can be used as blocking contacts on germanium radiation detectors,
8	with potential advantages over conventional contacts."
9	And also in the, sorry, the previous paragraph, at the bottom of
10	the first column, on page 590 of Luke, there's a sentence saying,
11	"Amorphous germanium blocking contacts on high purity germanium
12	detectors were investigated in 1977, but the devices showed large variations
13	in leakage currents."
14	JUDGE RUGGIERO: But doesn't the next sentence
15	specifically say that is referring to amorphous germanium that was deposited
16	by vacuum evaporations?
17	MR. MCHENRY: Yes, it does.
18	JUDGE RUGGIERO: And then it goes on to say that there are
19	other techniques used: Chemical vapor deposition. And then this paper
20	talks about sputtering techniques.
21	So, I mean, do those comments about the large variations of
22	leakage currents, we're supposed to understand it to apply to all those
23	different techniques?
24	MR. MCHENRY: No.

1	I think that it's just part of the overall context of this reference
2	and whether it's teaching equivalence; and that I think that it's, you know,
3	showing that in the past there is an understanding that they are different.
4	And then the next paragraph showing that there's a difference in
5	that there's possible advantages, and along with other knowledge from the
6	declaration that was submitted, statement in the specification that there's a
7	difference in energy resolution, that again the Examiner is relying on
8	equivalence.
9	But, you know, the facts that see in this reference, knowledge of
10	one of ordinary skill in the art, is that that rationale, that conclusion of
11	equivalence, is just not supported by the underlying facts.
12	And then my next point is that in terms of what the art would
13	actually indicate, what it would disclose and suggest to one of ordinary skill
14	in the art is not a combination, say of the base reference in Luke that would
15	provide structure with contacts going through amorphous germanium, all the
16	way through to the underlying semiconductor material.
17	The base reference itself, Hamacher, it shows in its figure, that
18	it really provides a kind of a thin disclosure, it just shows that you provide
19	the contacts that you can and these are the doped type of contacts, of
20	course and that you provide the structure all the way down to the semi-
21	conductor material.
22	But it doesn't explain why, or you know, the rationale for doing
23	so.
24	Now Luke, when it's discussing the amorphous germanium
25	contacts, it does speak of how it is desirable to or an advantage actually of
26	the amorphous germanium contacts is that not only do they provide the

26

1 contact material, but they also provide passivation material, and that there's 2 material between the contacts on top of the semi-conductor material, so that there is no cutting down or etching or exposure into the semiconductor material. 4 5 And as discussed in the brief, the Amman article also discussed this, and said that this is an advantage, because over in the doped contacts, the conventional-type contacts, that once they are made, you actually, it's desirable to have a passivation. 9 In fact, it says that you should have a passivation step to ensure 10 long-term stability of the contact. And the advantage of having the 11 amorphous germanium contact is that knowledge you provide a germanium 12 contact when you deposit it, but you also provide a passivation layer. My point being is that one of ordinary skill in the art, when 13 14 considering these facts, you know, these teachings, would understand that 15 one wouldn't want to provide the structures of the contacts through the amorphous germanium contact into the underlying semiconductor material; 16 because Luke actually teaches that you want to have it present, you want to 18 have a passivation layer. 19 You want to provide that protection and that long-term stability. 20 So when considering these teachings, you wouldn't simply -- I 21 think as the Examiner is arguing -- try to insert an amorphous germanium 22 contact, or substitute for a doped contact, and leave an unpassivated layer in 23 between. You would actually want that amorphous layer in between for its protection. 24 25 And also the Amman article says that you reduce the processing

steps and make the fabrication simpler.

1	And so, to sum that up, that again reference is the knowledge of
2	one of ordinary skill in the art doesn't support a conclusion of equivalence.
3	And with that removed, I think one of ordinary skill in the art
4	would have to consider the facts before them, and how they are used to
5	develop a rationale, how they arrive at the conclusion of obviousness to
6	combine the base reference in Luke to provide the features of Claim 1.
7	And looking at the actual reference as what they teach, they
8	don't support such a conclusion. As I said, Luke teaches that the passivation
9	layer is desired. And that's also supported in the Amman article.
10	JUDGE NAPPI: Does the primary reference have a passivation
11	layer?
12	MR. MCHENRY: No. I did not see one. It shows in the figure
13	on the first page that to develop from the semiconductor, you build up the
14	layers and you etch them. And then after that I believe the discussion gets
15	into the performance.
16	But it does not discuss passivation, or even why you have the
17	etching or cutting through the dope layer into the
18	JUDGE NAPPI: So wasn't Luke just saying if we used this
19	amorphous silicone, you can also get a passivation layer?
20	MR. MCHENRY: Amorphous silicone
21	JUDGE NAPPI: Why I'm sorry?
22	(Discussion was held off the record.)
23	JUDGE NAPPI: I'm sorry
24	MR. MCHENRY: Okay
25	JUDGE NAPPI: Amorphous germanium.

1 When you put Luke, isn't it just saying that's an advantage of 2 using the amorphous germanium, is that it gives you passivation? Why is it saying it's necessary, given the fact that the primary reference doesn't teach that it's necessary? 5 MR. MCHENRY: I think, well, actually I'll answer that by referring back to the Amman article that was provided as Supplemental Response submitted January 31st. It is also attached to the Appeal Brief. 8 Sorry --9 JUDGE NAPPI: Mm-hmm. We have it. 10 MR. MCHENRY: So on page 887, which is the second page of 11 the Amman reference, the very first paragraph, top of the first column, it's 12 discussing doped type contacts. And you know, such as the P contacts, the 13 N contacts. And then the first full paragraph on that first column. 14 JUDGE NAPPI: That starts off, "To produce"? 15 MR. MCHENRY: Yes, exactly. 16 JUDGE NAPPI: Okay. 17 MR. MCHENRY: Later in that paragraph, there's a sentence starting off, "Furthermore." It says, "Furthermore, the inter-contacted 18 19 surfaces of both contact types" -- and again, this is referring to the doped-20 type contacts -- "should be passivated to obtain long-term detector stability, 21 thereby necessitating additional processing steps," again, providing contacts 22 that when you add doped-type contacts is advantageous, in fact saying they 23 should be passivated to obtain long-term detector stability. And another 24 advantage is that it simplifies the process. 25 JUDGE MARTIN: Isn't the date of that article 2007, well after 26 your filing date?

1	MR. MCHENRY: Yes, it is.
2	JUDGE MARTIN: Thank you.
3	Another question. Does the Applicant require passivation in its
4	device? Is it disclosed as requiring passivation?
5	MR. MCHENRY: We'll quickly refer to Claim 1, I want to say
6	no, that it's not the feature that is recited in Claim 1.
7	JUDGE MARTIN: Okay. So it's not just described as required
8	in the application, so far as you can recall?
9	MR. MCHENRY: No.
10	JUDGE MARTIN: Okay.
11	Have the Applicants discovered that you don't need a
12	passivation layer all the time?
13	MR. MCHENRY: You know, referring to the Declaration and
14	again, the disclosure of the application and I think you say is that's the
15	advantage of the invention is that there was this thinking and knowledge
16	that amorphous germanium layers actually could reduce energy resolution
17	when they are provided, even though they are serving as passivation layer in
18	between the contacts.
19	And the inventors here discovered that if you use the
20	amorphous germanium contacts and you etch them, remove them, the
21	amorphous germanium contacts, down to the underlying semiconductor
22	material, that you actually could see improved performance, such as energy
23	resolution.
24	JUDGE MARTIN: Is energy resolution a function of leakage
25	current? I thought I saw

1	MR. MCHENRY: I believe that was discussed in the
2	Declaration by Mr. Protic.
3	JUDGE MARTIN: Okay. And Declaration also says that, in
4	paragraph 10, that the typical operating temperature of detector made of
5	germanium is 77 degrees Kelvin, and constantly low. As a result, the
6	leakage current is low.
7	So it doesn't sound like leakage current's a problem at that
8	expected operating temperature. So I wouldn't expect, or think you wouldn't
9	expect I'm sorry, what's the other concept we were looking for
10	sensitivity? Was that it?
11	Oh, I'm sorry, energy resolution. They would expect that to be
12	poor if the dark current is not a problem at the expected operating
13	temperature.
14	MR. MCHENRY: I understand.
15	I think to answer your question, I would refer to the Appeal
16	Brief, pages 6 to 7, which in turn refers to the page 889 of the Amman
17	publication, which is talking about also cycling of the temperatures for these
18	devices, and that the temperature cycling can lead to increased leakage
19	currents, which can then lead to a degradation of energy resolution.
20	So it's perhaps a single operating temperature is a factor for
21	leakage current, but also what you see with the temperature cycling can lead
22	to increased leakage currents and degradation performance.
23	Are there any other questions?
24	JUDGE RUGGIERO: No.
25	JUDGE NAPPI: Thank you very much for your time.
26	MR. MCHENRY: Thank you.

Appeal 2009-012467 Application 10/511,734

Whereupon, at 10:19 a. m. the hearing was concluded.

Whereupon, at 10:19 a. m. the hearing was concluded.

Market State State